NSN 5961-01-485-2430

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-485-2430 **Inclosure Material:** Ceramic **Overall Length:** Between 1.520 inches and 1.540 inches **Overall Height:** Between 0.310 inches and 0.495 inches **Overall Width:** Between 0.990 inches and 1.050 inches **End Application:** Patriot missile **Mounting Facility Quantity: Internal Configuration:** Field effect **Mounting Method:** Unthreaded hole **Features Provided:** Electrostatic sensitive **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 drain to source voltage and 1000.0 drain to gate voltage **Current Rating Per Characteristic:** 15.60 amperes off-state current, peak **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**